Switched-capacitor filters



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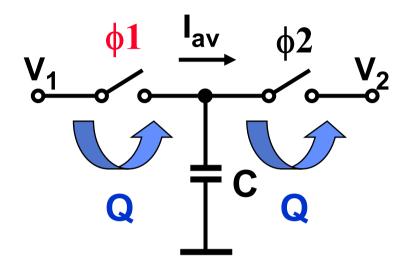


Switched-Capacitor Filters

- Introduction : principle
- Technology:
 - MOS capacitors
 - MOST switches
- SC Integrator
 - SC integrator: Exact transfer function
 - Stray insensitive integrator
 - Basic SC-integrator building blocks
- SC Filters: LC ladder / bi-quadratic section
- Opamp requirements
 - Charge transfer accuracy
 - Noise
- Switched-current filters

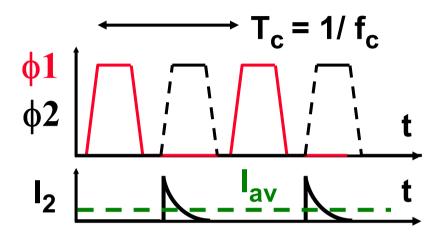
McCreary, JSSC Dec 75, 371-379 Gregorian, IEEE Proc. Aug 83, 941-986

Principle



$$I_{av} = \frac{Q_{av}}{T_c} = \frac{C(V_1 - V_2)}{T_c}$$

$$I_{av} = \frac{(V_1 - V_2)}{R}$$

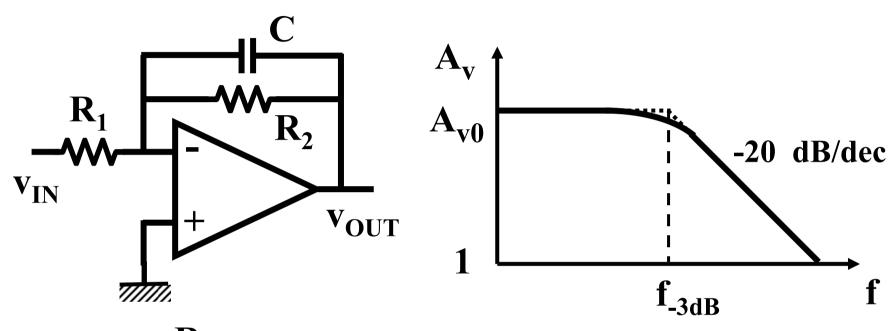


- Non overlapping clocks
- Switches are MOSTs

$$R = \frac{T_c}{C} = \frac{1}{f_c C}$$

For C = 1 pF & f_c = 100 kHz R = 10 M Ω

Low-Pass Filter with R's and C



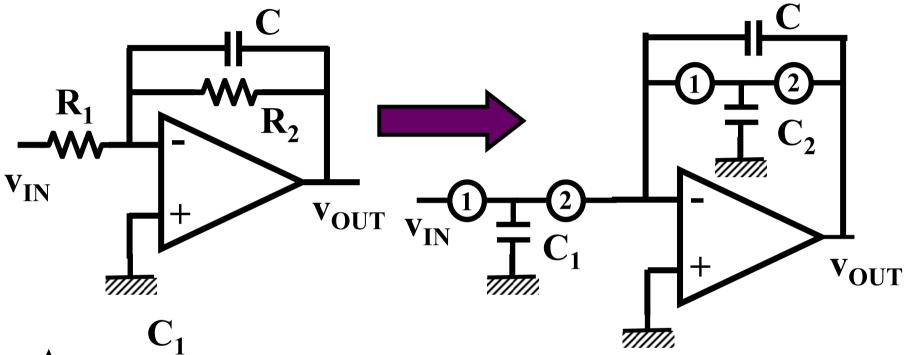
$$A_{v0} = \frac{R_2}{R_1}$$

$$\mathbf{f}_{-3db} = \frac{1}{2\pi \mathbf{R} \cdot \mathbf{C}}$$

Ratio's of R: 0.5% accuracy

Absolute value of RC: 20 % accuracy

Low-Pass Filter with switched C's



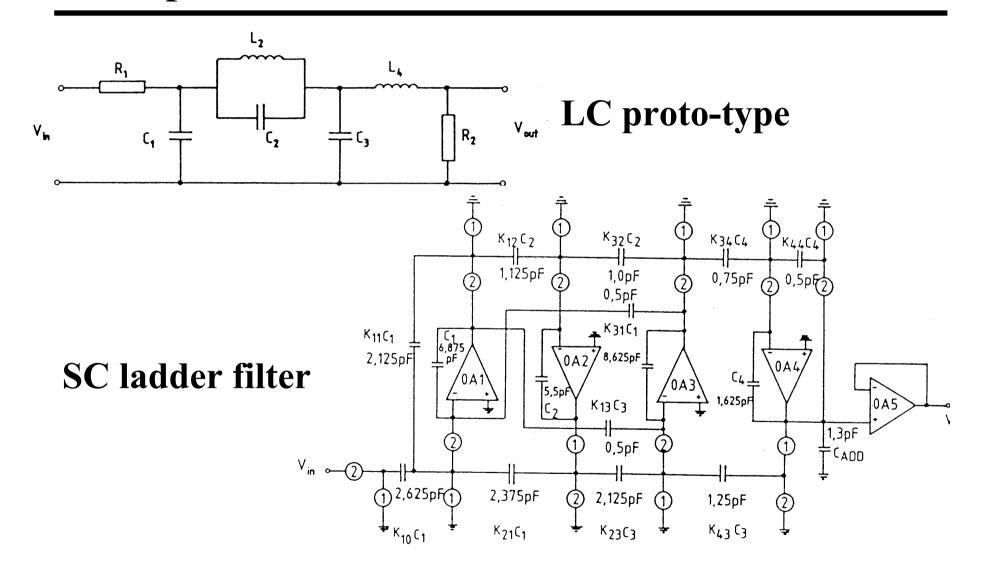
$$\mathbf{A_{v0}} = \frac{\mathbf{C_1}}{\mathbf{C_2}}$$

$$\mathbf{f_{-3db}} = \frac{\mathbf{f_c}}{2\pi} \frac{\mathbf{C_2}}{\mathbf{C}}$$

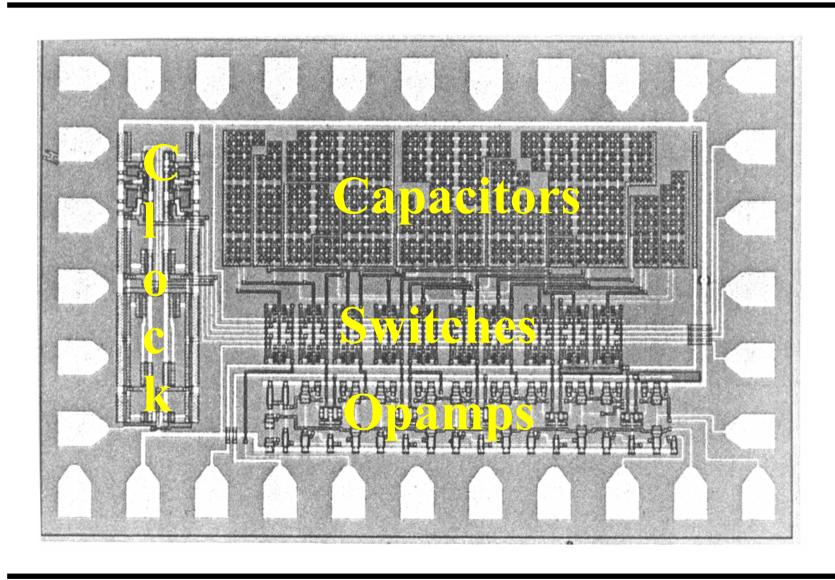
High accuracy: only ratio's of C: 0.2% Only capacitors to drive: low power! Tunable & easy to integrate!

But: only for frequencies << f_c

Example of 4th-Order SC Low-Pass filter



4th-Order SC Low-Pass filter

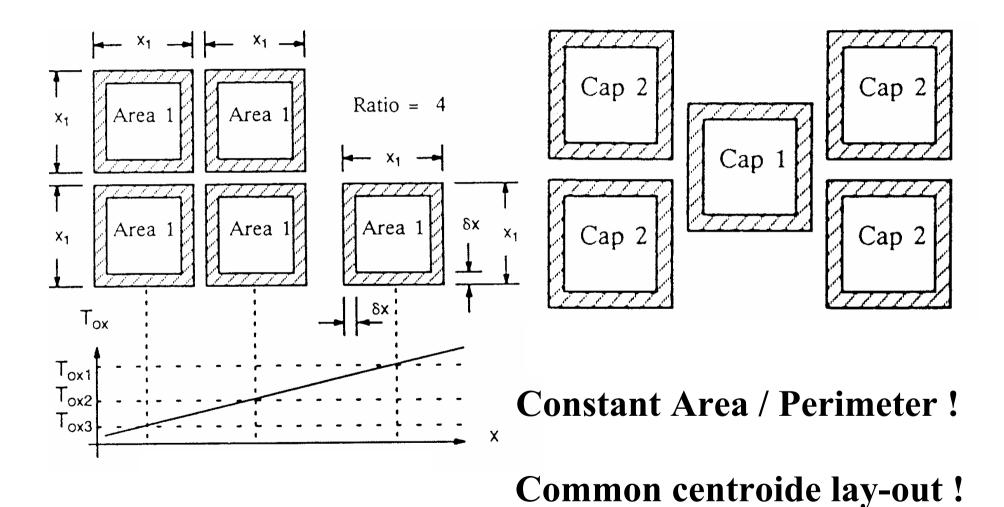


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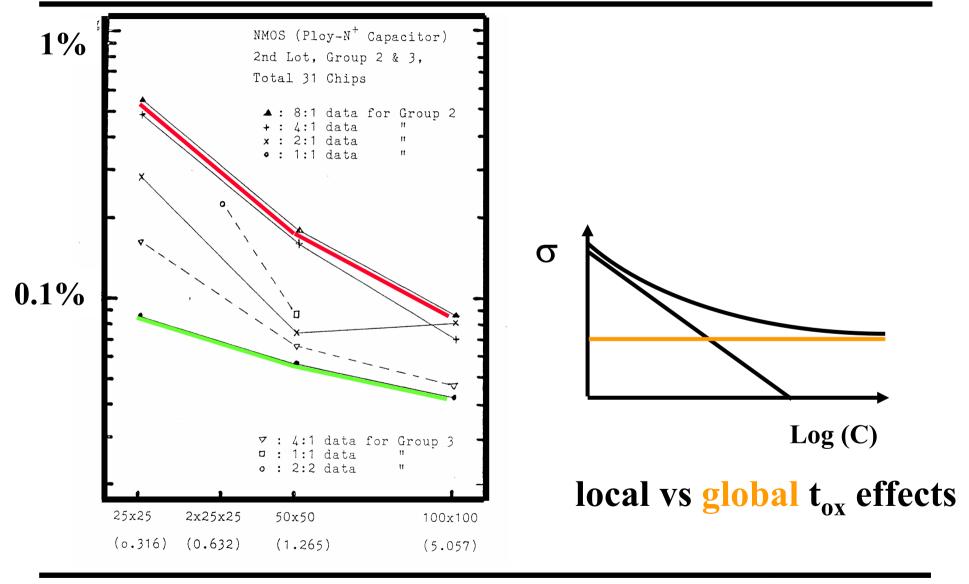
McCreary, JSSC Dec 75, 371-379 Gregorian, IEEE Proc. Aug 83, 941-986

Capacitor Matching

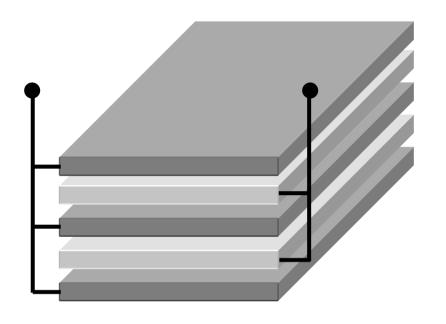


Willy Sansen 10-05 N1710

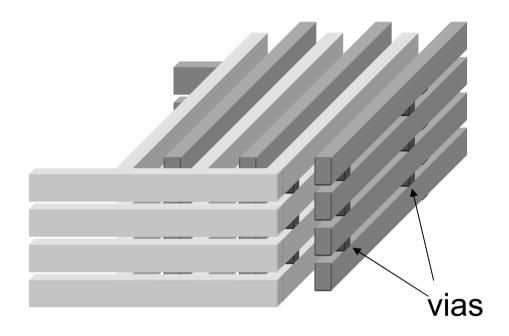
Random Error (σ)



Capacitances in nanometer CMOS



- MIM capacitors
- 5 metal layers, 0.35 fF/ μ m²
- Excellent matching



- Digital technology, no MIM cap.
- lateral metal-metal capacitance
- 8 metal layers, 1.7 fF/ μ m²
- Good matching

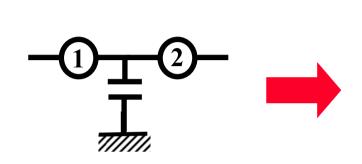
Aparicio, JSSC March 02, 384-393

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A MOST as a switch



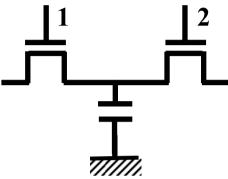
$$R_{on} = \frac{1}{KP_n \frac{W}{L} (V_h - V_T - V_{sign})}$$

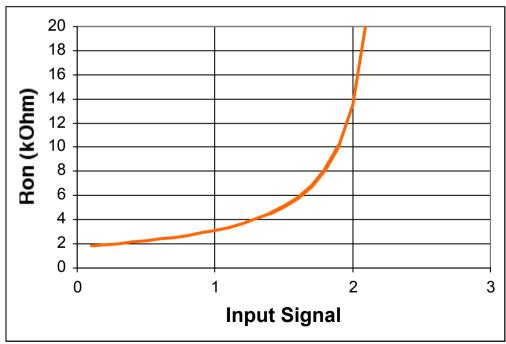
$$W=2~\mu m~L=0.7~\mu m$$

$$KP_n=80~\mu A/V^2$$

$$V_T=0.7~V$$

$$V_h = 3 V$$





Double Switch or transmission gate

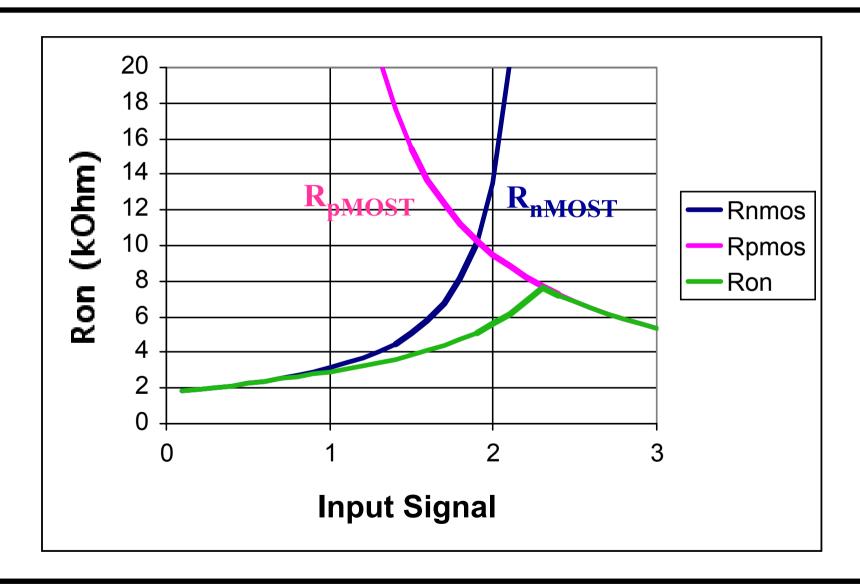
Switch: $v_{in} \xrightarrow{\Phi_1} v_{in} \xrightarrow{\Phi_1} c$

nMOST:
$$V_{in} < V_{DD}-V_{GS,n} \approx V_{DD} - 0.7 V$$

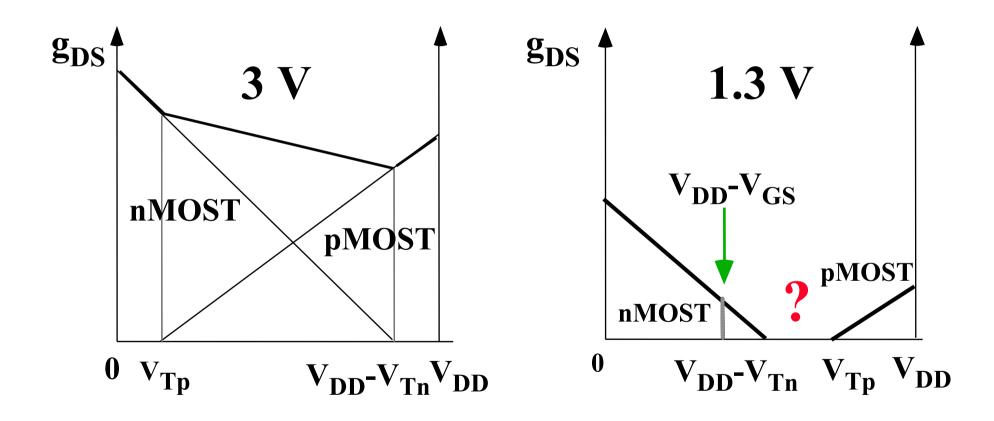
pMOST:
$$V_{in} > V_{GS,p} \approx 0.7 \text{ V}$$

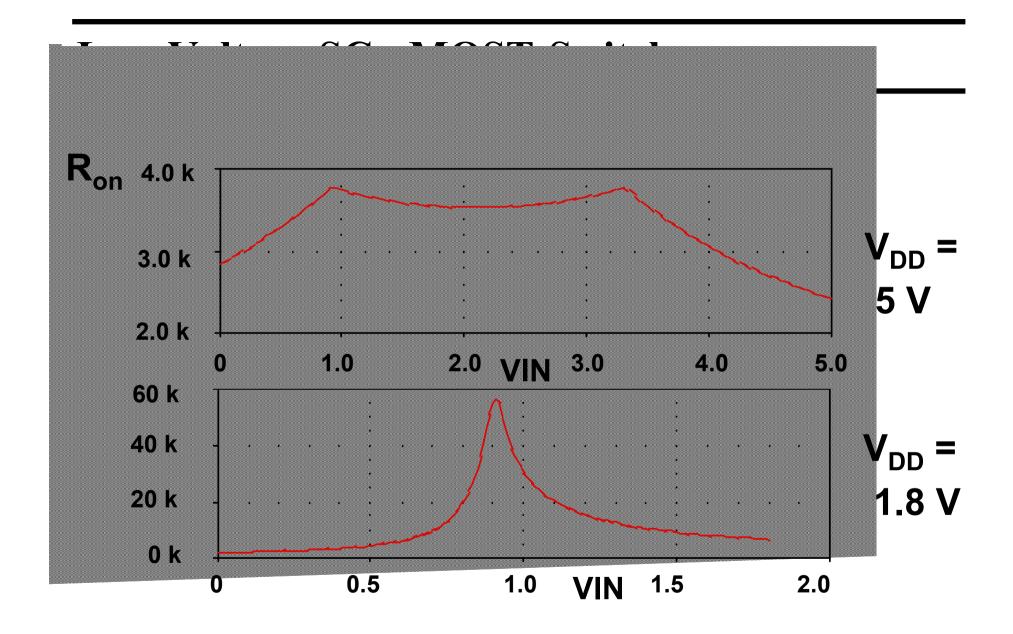
Minimum
$$V_h = V_{DD} : V_{DD} - V_{GS,n} = V_{GS,p} = V_{DD} > 1.4 V$$

Double Switch

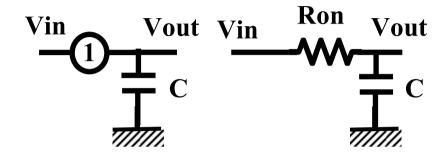


Low Voltage SC: MOST-Switch





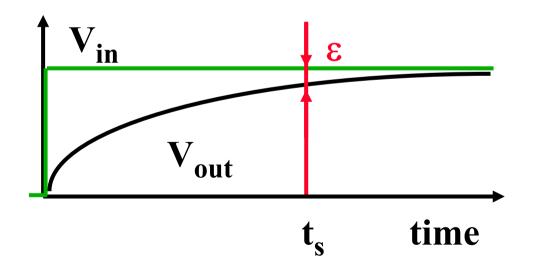
Time constant of Ron



$$V_{out} = V_{in} (1-exp(-\frac{t}{RC}))$$

$$t_{s} = RC \ln(1/\epsilon)$$

$$t_{s} \approx 7 RC \text{ for } \epsilon = 0.1 \%$$



Speed ↓ if large C (low noise) large R (small switch)

Maximum frequency of operation

For W/L = 2 and V_{GS} - $V_T \approx 1 V$

 $R_{on} \approx 10 \text{ k}\Omega$

For $C \approx 1 \text{ pF}$

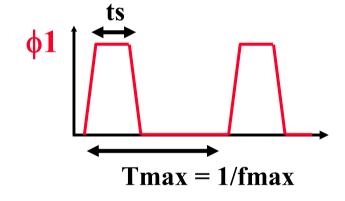
For $\varepsilon \approx 0.1\%$

 $t_s = 7 \text{ RC} \approx 70 \text{ ns}$

 $T_c = 140 \text{ ns} \Rightarrow f_{\text{max}} \approx 7 \text{ MHz}$

Due to only one switch

 \Rightarrow practical f_{max} : 1-10 MHz



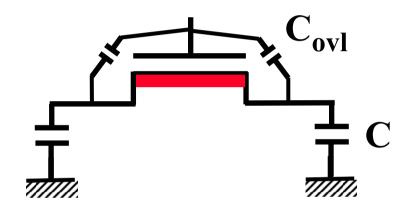
$$L \Psi \Rightarrow R_{on} \Psi$$

Minimum frequency of operation

$$V_{C} = 0 \qquad \qquad \Delta V_{C} \qquad \qquad \Delta V_{C} \qquad \qquad Leakage \ i = C \ \frac{dV_{C}}{dt} \qquad \qquad i \ is \ 10 \ nA/cm^{2} \ at \ 25^{o} \qquad \qquad is \ 10 \ \muA/cm^{2} \ at \ 125^{o} \qquad \qquad is \ 10 \ \muA/cm^{2} \ at \ 125^{o} \qquad \qquad For \ 10x1 \ \mum: \ 2 \ fA \ (25^{o}) \qquad \qquad \Delta V_{c} = 1\% \ of \ 0.1 \ V \ or \ \Delta V_{c} = 1 \ mV \qquad \qquad or \ 2 \ pA \ (125^{o}) \qquad \qquad dt = T_{c}/2 \quad with \ T_{c} = 1/f_{cmin} \qquad \qquad i \qquad \qquad dV_{c} = 4 \ Hz \ or \ 4 \ kHz \ (125^{o})$$

Clock Feed-Through

Overlap Capacitors



$$C_{ovl} \approx W C_{ovlo}$$

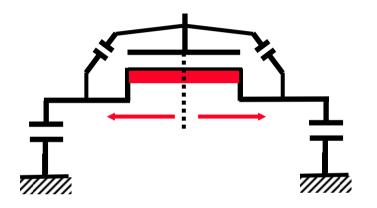
$$W \uparrow \Rightarrow R \downarrow but C_{ovl} \uparrow$$

Example:
$$W = 3\mu m$$
 L = 0.7 μm
 $C_{ovlo} = 0.5$ fF/ μm
 $\Rightarrow C_{ovl} \approx 1$ fF

$$\Delta V$$
: $Q = C_{ovl} (V_h - V_l) \approx 1 \text{fF. } 3V \approx 3 \text{fC}$
 $\Rightarrow \Delta V \approx \frac{Q}{C} \approx 3 \text{fC} / 1 \text{pF} \approx 3 \text{ mV}$

Charge redistribution

Inversion layer charge



$$Q_m \approx C_{ox}WL(V_h-V_{sign}-V_T)$$

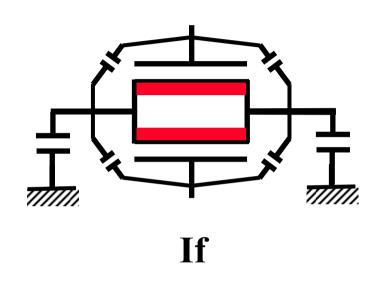
Ex. W = 3
$$\mu$$
m L = 0.7 μ m
 $C_{ox} = 1.6 \text{ fF/}\mu\text{m}^2$
 $V_T = 0.7V V_{sign} = 1.5V$
 $\Rightarrow Q \approx 6 \text{ fC}$

 ΔV : Half is stored in each cap

$$\Rightarrow \Delta V \approx Q/2C \approx 3 \text{ fC/1pF} \approx 3 \text{ mV}$$

Total:
$$\Delta V \approx 10 \text{ mV/pF}$$
 $C \uparrow \Rightarrow CD \downarrow \text{ Speed} \downarrow \text{ Power} \uparrow$

Clock injection & Charge redistribution

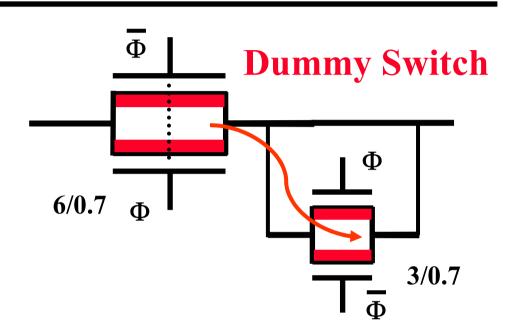


$$C_{ovl,n} = C_{ovl,p}$$

No Clock FT!

Problems: matching

$$W_n = W_p$$
?



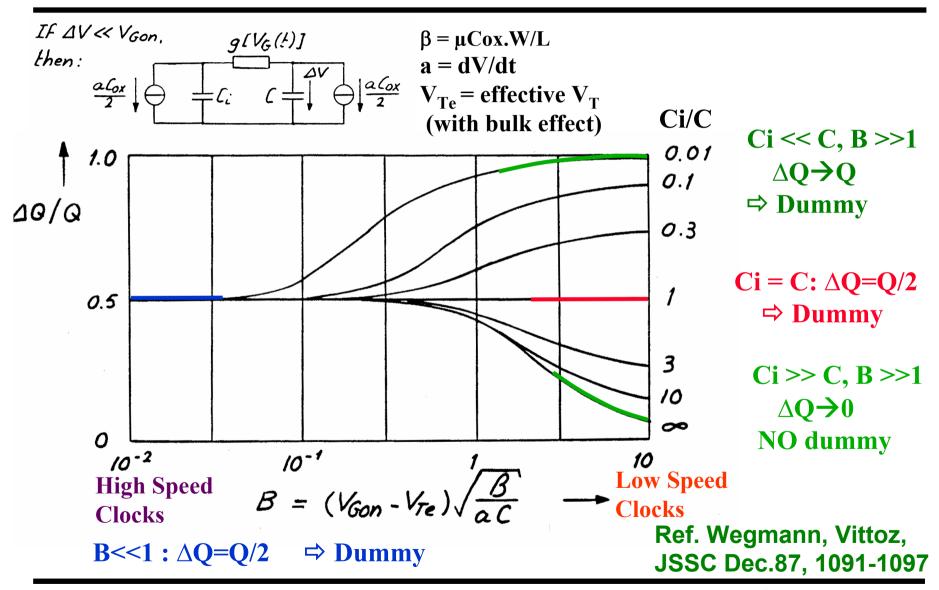
OK if Q is split equal 1/2

Problems: clock skew

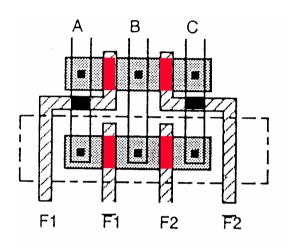
rise/fall time

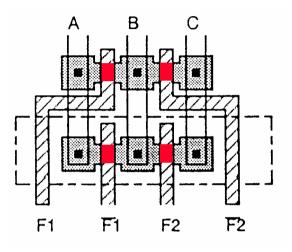
impedance

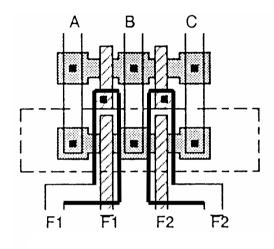
Quantitative Charge Redistribution



Layout considerations







Parasitic C

U

CFT

Reduce C_{ox} area

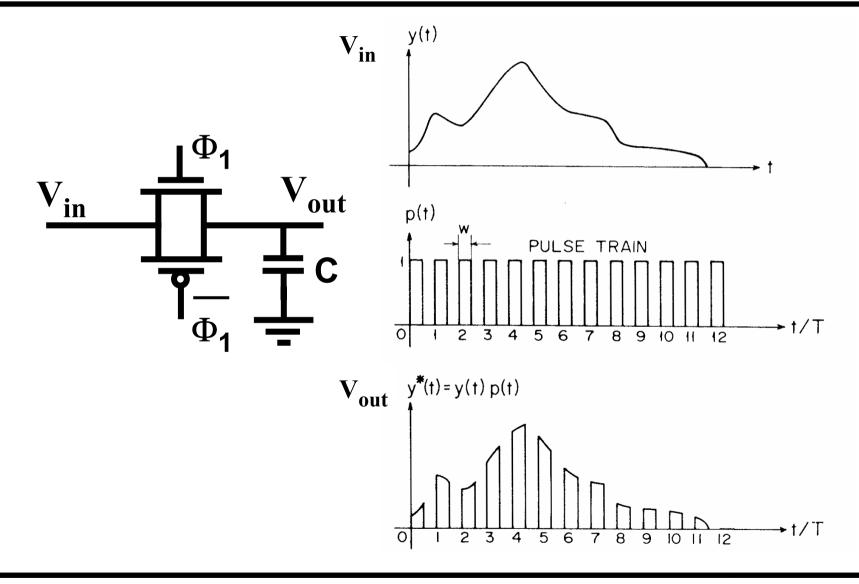
Use metal to 'shield' clock lines

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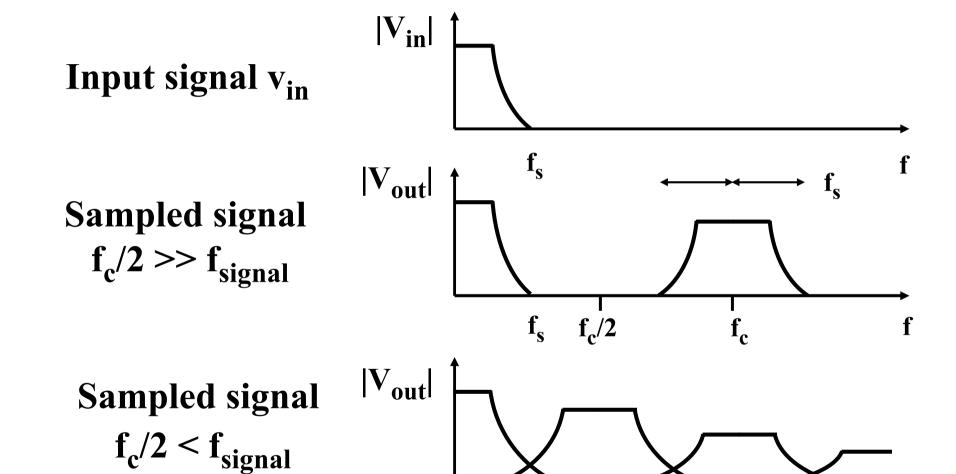
McCreary, JSSC Dec 75, 371-379 Gregorian, IEEE Proc. Aug 83, 941-986

Sampling analog signals



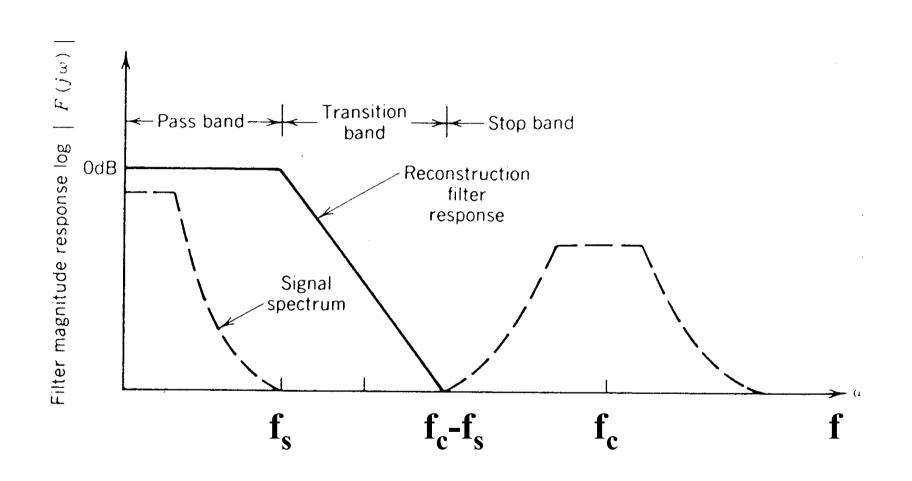
Spectra

Nyquist!

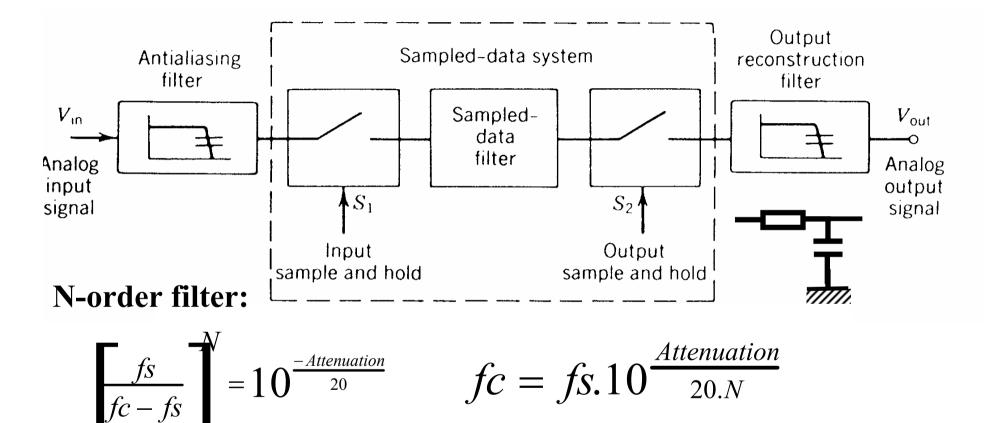


 $3f_c$ f

Anti-Aliasing filter



Anti-aliasing / Reconstruction



Ex. Attenuation = 40 dB; fs = 10 kHz; $N = 1 \Rightarrow fc = 1 \text{ MHz}$

Sampled Data Basics: z-transform

Analog System: $s = j\omega$

$$\frac{\mathbf{V_{out}}}{\mathbf{V_{in}}} = \frac{1}{1 + \mathbf{sRC}}$$

z-TRANSFORM

SEQUENCE

$$a X(z) + b V(z)$$

$$ax(n) + bv(n)$$

$$z^{-n_1} Y(z)$$

$$y(n-n_1)$$

$$b^n y(n)$$

Sampled data: z-transforms

1 delay is
$$z^{-1}$$

1 delay is
$$z^{-1}$$

 $z = e^{j\omega T_c} = e^{j\frac{2\pi f}{f_c}}$

$$-z\frac{dY(z)}{dz}$$

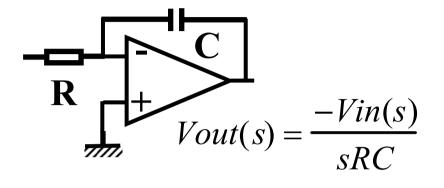
$$Y(z^{-1})$$

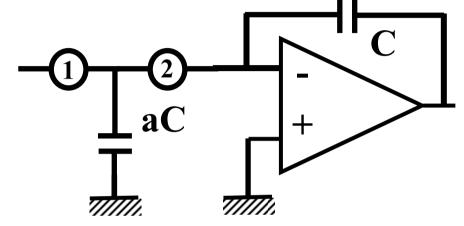
$$y(-n)$$

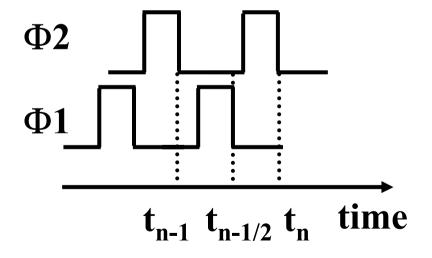
$$x(n) * v(n)$$

$$e^{j\omega T_c} = 1 + j\omega T_c + \frac{(j\omega T_c)^2}{2} + \dots$$
 if $\omega T_c << 1$

SC-Integrator in phase 1

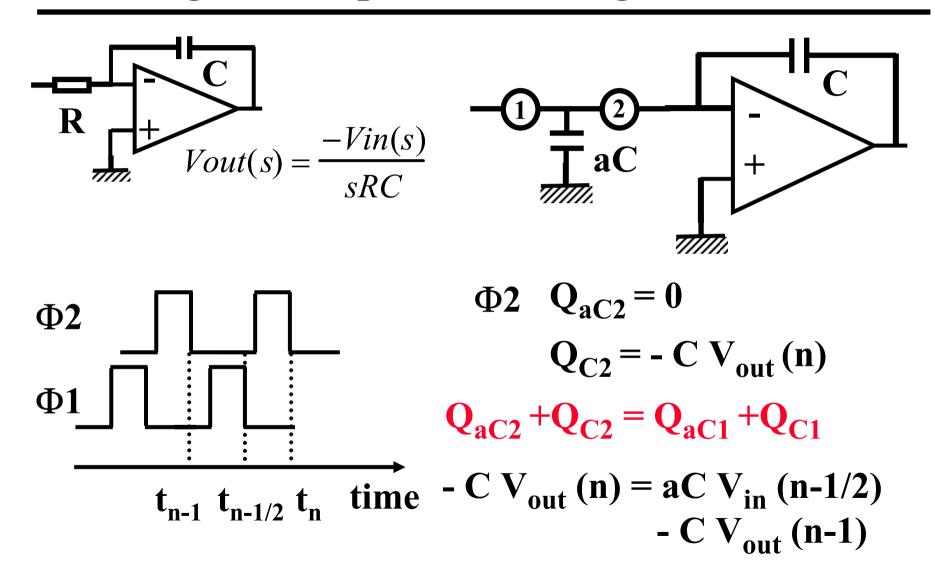






$$Φ1$$
 $Q_{aC1} = aC V_{in}(n-1/2)$
 $Q_{C1} = -C V_{out}(n-1)$
 $V_{out}(n-1/2) = V_{out}(n-1)$

SC-Integrator in phase 2: charge conservation



SC-Integrator: approximate transfer function

- C
$$V_{out}(n) = aC V_{in}(n-1/2) - C V_{out}(n-1)$$

 $V_{out}(n-1) = z^{-1} V_{out}$

$$\Rightarrow$$
 C.V_{out} = z⁻¹ C V_{out} - z^{-1/2} aC V_{in}

$$\frac{V_{out}}{V_{in}} = -a \frac{z^{-1/2}}{1 - z^{-1}}$$
 $z^{-1} = e^{-j\omega T_c} \approx 1 - j\omega T_c$

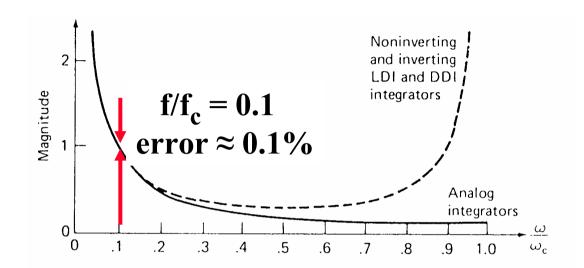
$$\Rightarrow \frac{Vout}{Vin} \approx -\frac{a(1-j\omega Tc(2))}{j\omega Tc} \approx -\frac{a}{j\omega Tc} \qquad \text{Integrator}$$

$$RC = \frac{T_c}{a}$$

Exact Transfer function

$$H(z) = -\frac{az^{-1/2}}{1 - z^{-1}}$$

$$H(e^{j\omega T_c}) = -\frac{ae^{-j\omega T_c/2}}{1 - e^{-j\omega T_c}}$$



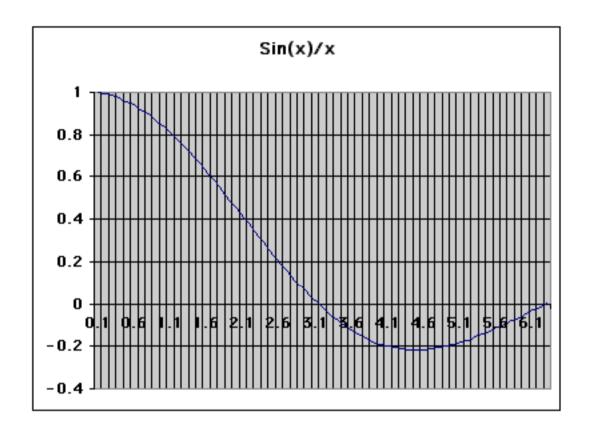
$$H(e^{j\omega T_c}) = -\frac{a}{e^{j\omega T_c/2} - e^{-j\omega T_c/2}}$$

$$H(e^{j\omega T_c}) = -\frac{a}{j\omega T_c} \frac{\omega T_c/2}{\sin(\omega T_c/2)}$$

Euler's relationship:

$$\sin(x) = \frac{e^{+jx} - e^{-jx}}{2j}$$

The sin(x)/x function



$$\sin(x) \approx x - \frac{x^3}{3} + \dots$$

$$\frac{\sin(x)}{x} \approx 1 - \frac{x^2}{3} + \dots$$

For
$$x = 0.1$$

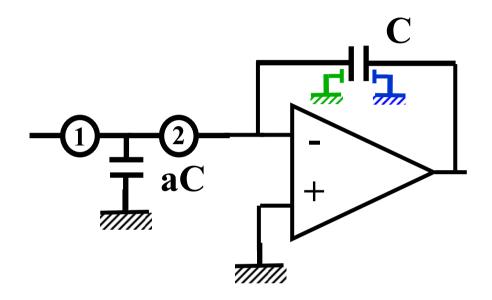
 $\sin(x)/x \approx 1 - 0.003$

For
$$x = 0.05$$

 $\sin(x)/x \approx 1 - 0.0008$
 $\approx 1 - 0.001$

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Stray Capacitances

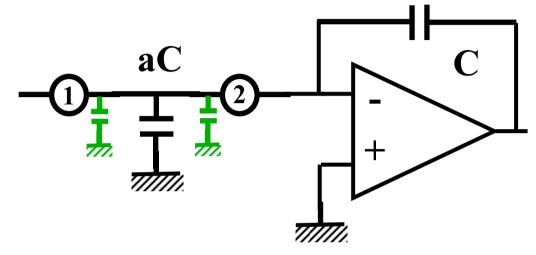


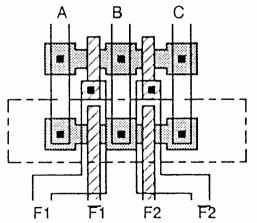
Stray Cap at input:

Substrate coupling Continuous time PSRR very bad **Stray Cap at output:**

Cp is extra load for opamp

Stray Capacitances



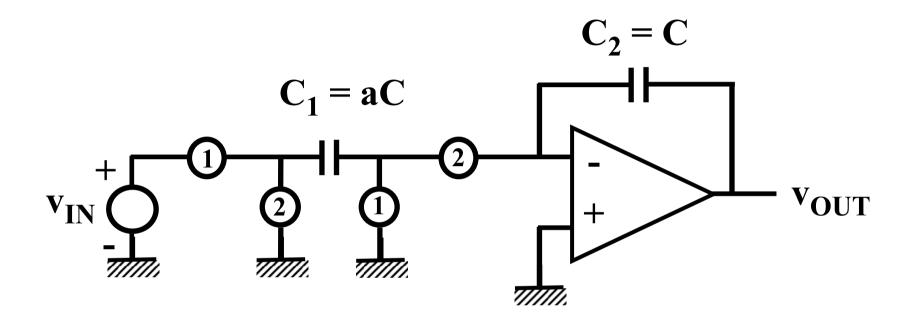


$$Cp \approx 2.C_{jS}$$
. Area $\approx 20 \text{ fF}$

$$Gain = \frac{aC + 2Cp}{C}$$

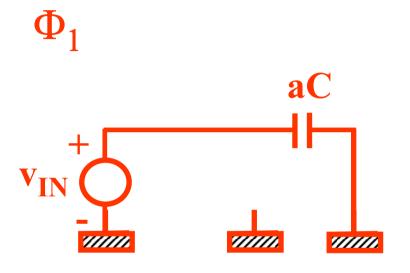
$$error \approx \frac{2Cp}{aC} \approx 5 - 10\%$$

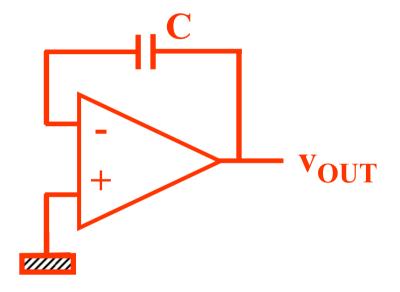
Stray Insensitive SC integrator



$$\mathbf{A_{v}} = \frac{\mathbf{C_{1}}}{\mathbf{C_{2}}} = \mathbf{a}$$

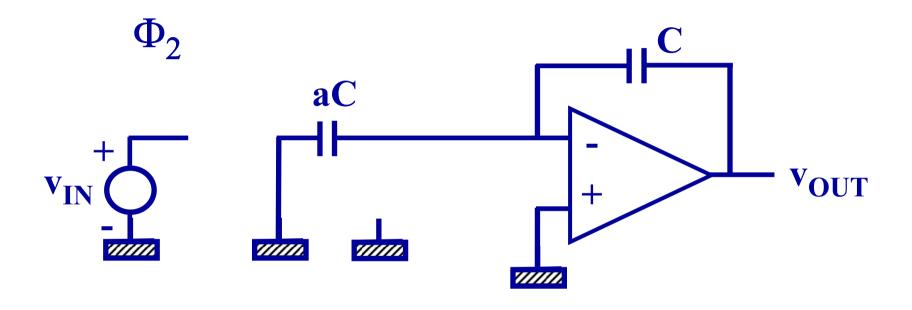
Stray Insensitive SC integrator





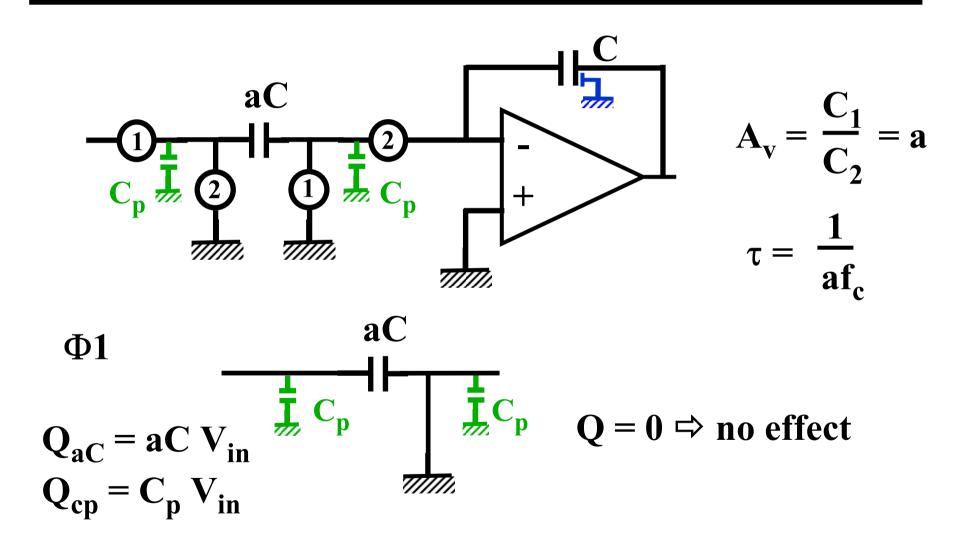
$$\mathbf{A_{v}} = \frac{\mathbf{C_{1}}}{\mathbf{C_{2}}} = \mathbf{a}$$

Stray Insensitive SC integrator

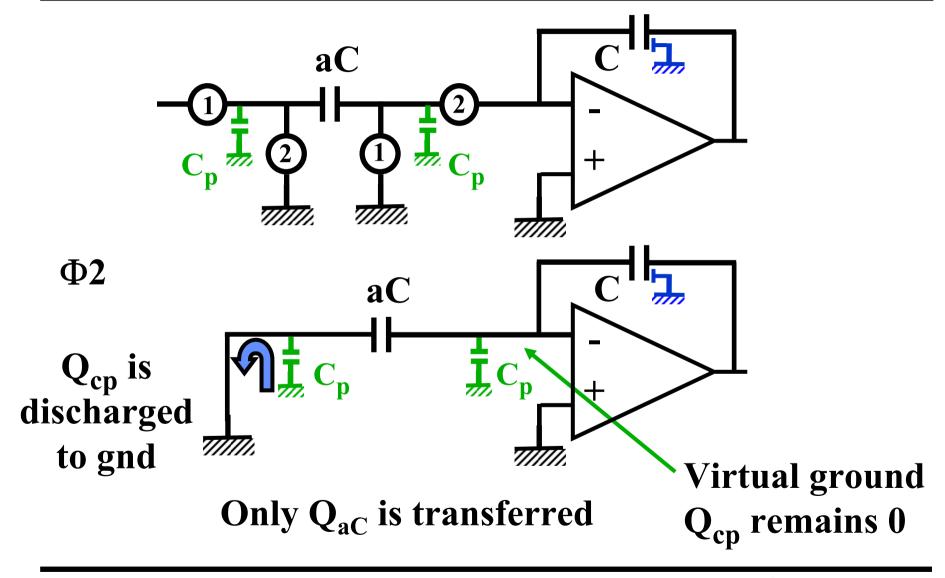


$$\mathbf{A_{v}} = \frac{\mathbf{C_{1}}}{\mathbf{C_{2}}} = \mathbf{a}$$

Stray Insensitive Integrator during phase 1

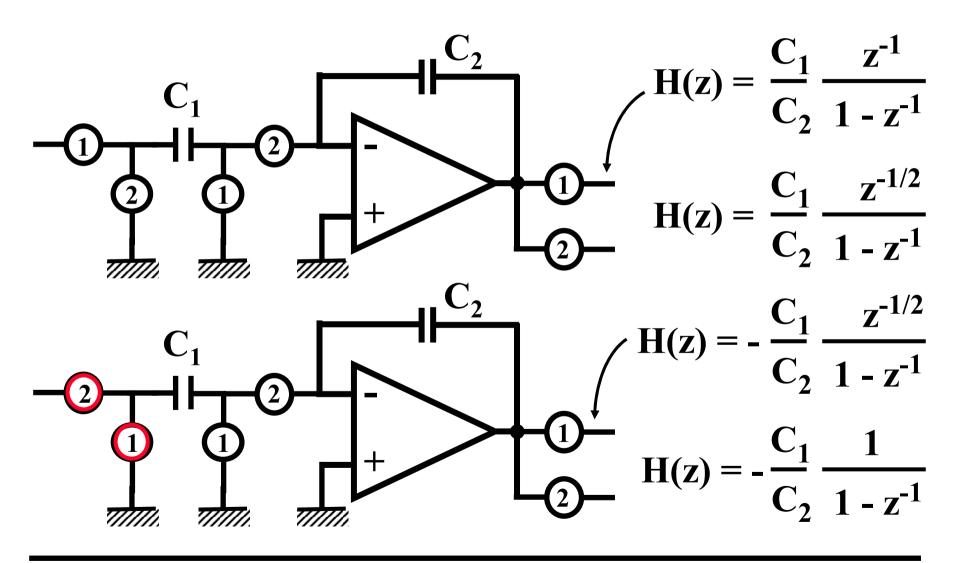


Stray Insensitive Integrator during phase 2

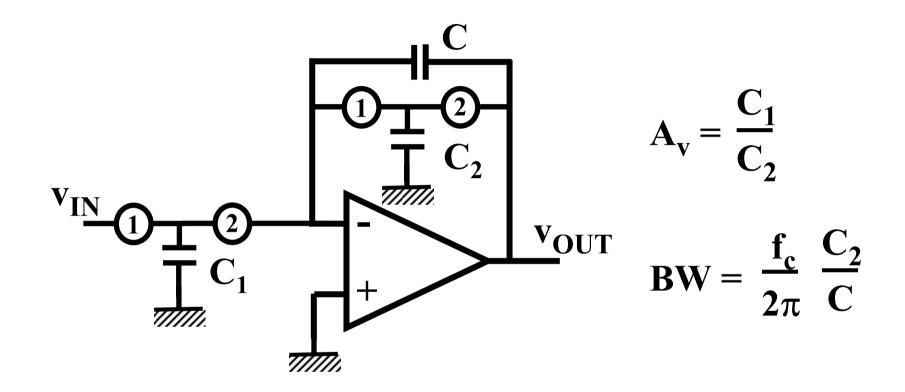


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Loss-less Integrators

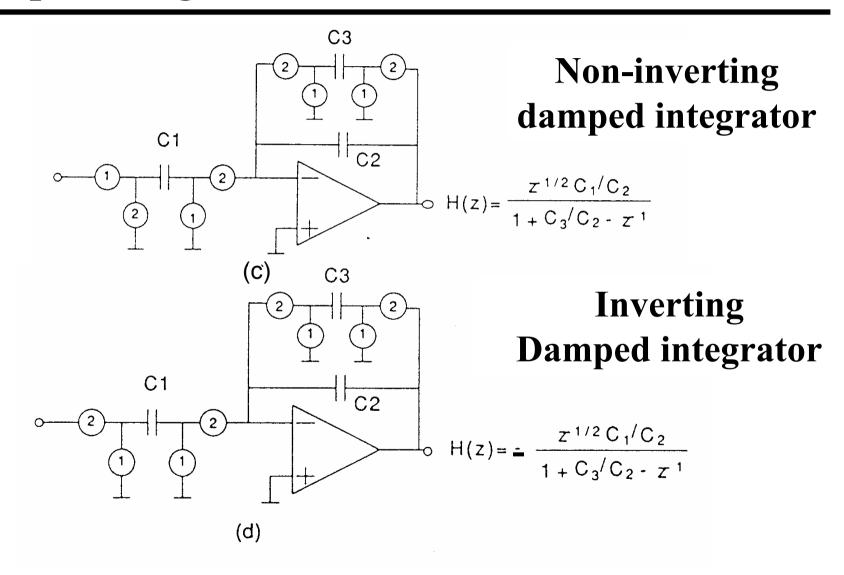


Low-pass filter of 1st order

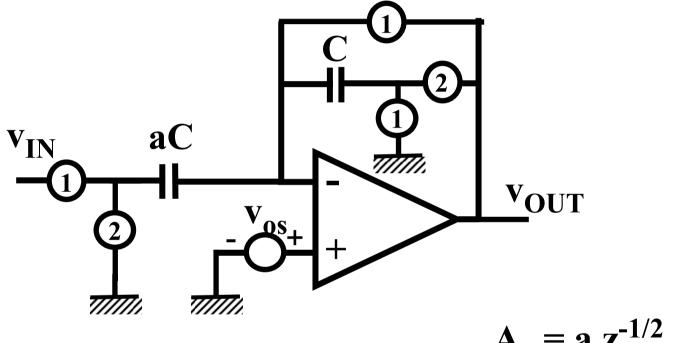


Damped because of R//C!

Damped integrators



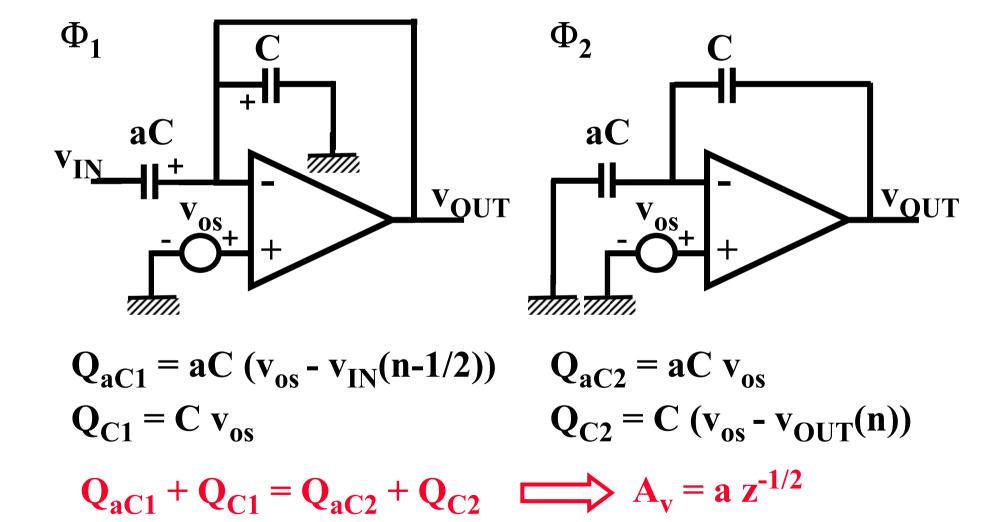
Offset compensation



 $A_v = a z^{-1/2}$ independent of v_{os}

Gregorian, IEEE Proc. Aug 83, 941-986

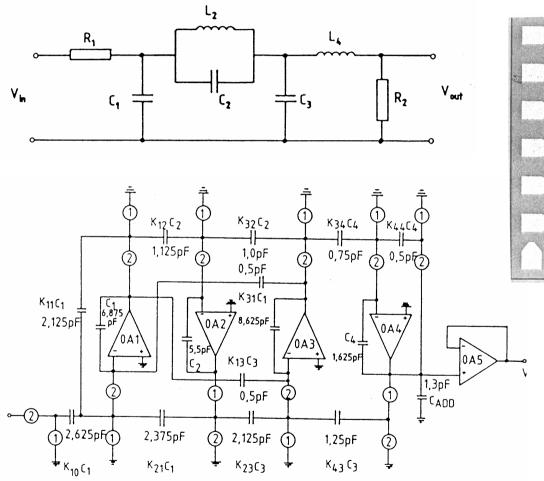
Offset compensation

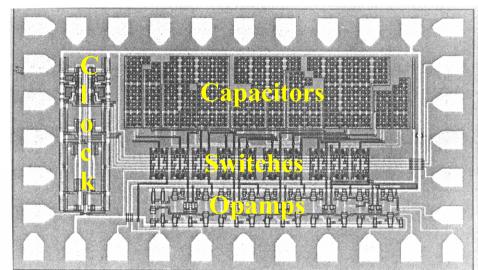


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Gregorian, Temes, Analog MOS Integrated Circuits for Signal Processing, Wiley, 1986 Laker, Sansen, Design of Analog Integrated Circuits and Systems, McGrawHill, 1994 Johns, Martin, Analog Integrated Circuit Design, Wiley 1997

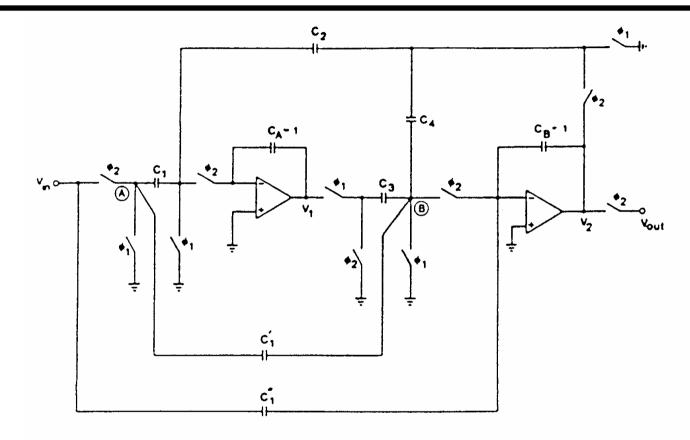
4th Order SC low-pass ladder filter





Clock freq 100 kHz **Cut-off** 5 kHz Pass ripple 0.25dB **Stop reject** >45 dB **Power** 190µW (± 2.5V) S/N 75 dB 0.25% Harm dist 0.9 mm² Area

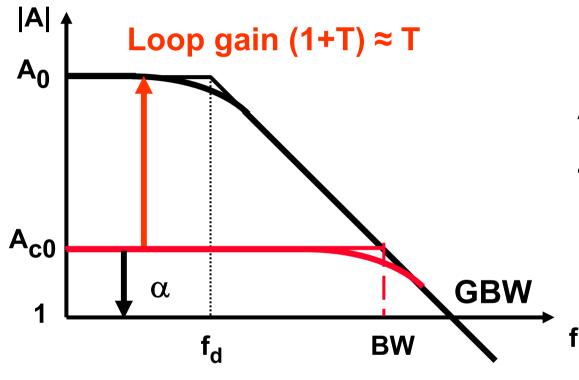
Biquadratic filter



$$H(z) = -\frac{a_2z^2 + a_1z + a_0}{b_2z^2 + b_1z + b_0} = -\frac{(C_1' + C_1")z^2 + (C_1C_3 - C_1' - 2C_1")z + C_1"}{(1 + C_4)z^2 + (C_2C_3 - C_4 - 2)z + 1}$$

- Introduction: principle
- Technology:
 - MOS capacitors
 - MOST switches
- SC Integrator
 - SC integrator: Exact transfer function
 - Stray insensitive integrator
 - Basic SC-integrator building blocks
- SC Filters: LC ladder / bi-quadratic section
- Opamp requirements
 - Charge transfer accuracy
 - Noise
- Switched-current filters

Opamp parameters



Feedback factor α

$$A_{c0} = 1/\alpha$$

$$T = A_0 / A_{c0} = \alpha A_0$$

$$GBW = \frac{g_{m}}{2\pi C_{eff}}$$

$$BW = \alpha GBW$$

Static error

$$V_{out, t = \infty} = -\frac{Ao.Vstep}{1 + \alpha.Ao}$$

$$\varepsilon_{s} = \frac{Vstep/\alpha - Vout}{Vstep/\alpha} = 1 - \frac{Ao}{1 + Ao.\alpha} \approx \frac{1}{\alpha.Ao}$$

Minimum Gain

$$Ao > \frac{1}{\alpha \cdot \mathcal{E}_S}$$

$$\varepsilon = 0.05\%$$

$$A_0 \approx 1-10k$$

$$\approx 60.80 \text{ dP}$$

$$\varepsilon = 0.05\%$$

$$\Box$$

$$A_0 \approx 1-10k$$

$$\approx 60-80 \text{ dB}$$

Dynamic error

$$\mathcal{E}_D = EXP(-\frac{\alpha.gm.ts}{C_{L,ef}})$$

$$\mathcal{E}_D = EXP(-\alpha.2\pi.GBW.ts)$$

$$GBW = \frac{gm}{2\pi C_{L,ef}}$$

$$t_S = \frac{1}{2f_c}$$

$$GBW = \frac{1}{\alpha.2\pi.ts} \ln(\frac{1}{\mathcal{E}_D}) = \frac{2f_c}{2\pi.\alpha} \ln(\frac{1}{\mathcal{E}_D})$$

Minimum GBW:
$$GBW > \frac{f_c}{\pi \cdot \alpha} \ln(\frac{1}{\mathcal{E}_D})$$
 $\varepsilon = 0.05\%$ $\varepsilon = 0.05\%$

$$\varepsilon = 0.05\%$$

$$\Box$$

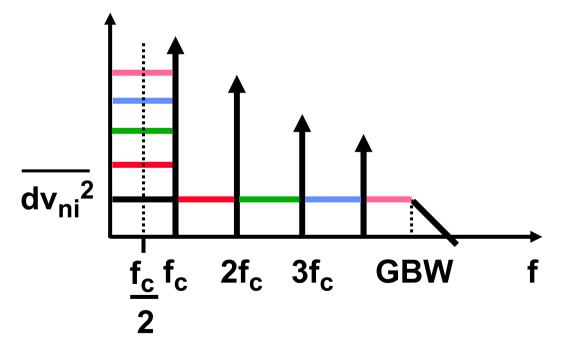
$$GBW \approx 2-3*f_c$$

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kT/C versus kTR noise

Narrow-band noise >> noise density : $dv_{ni}^2 = 4kT R df$

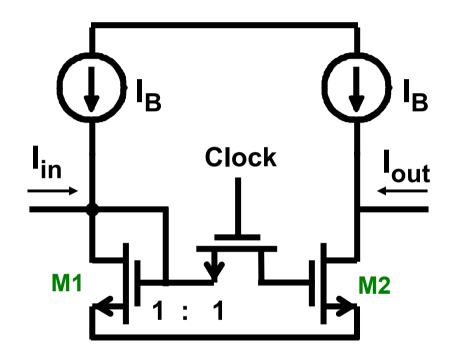
Wide-band noise >> integrated noise : $\frac{--}{v_{ni}^2} = \frac{kT}{C}$



$$v_{ni}^2 = \frac{kT}{C} \frac{GBW}{f_c/2}$$

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Switched-current delay block

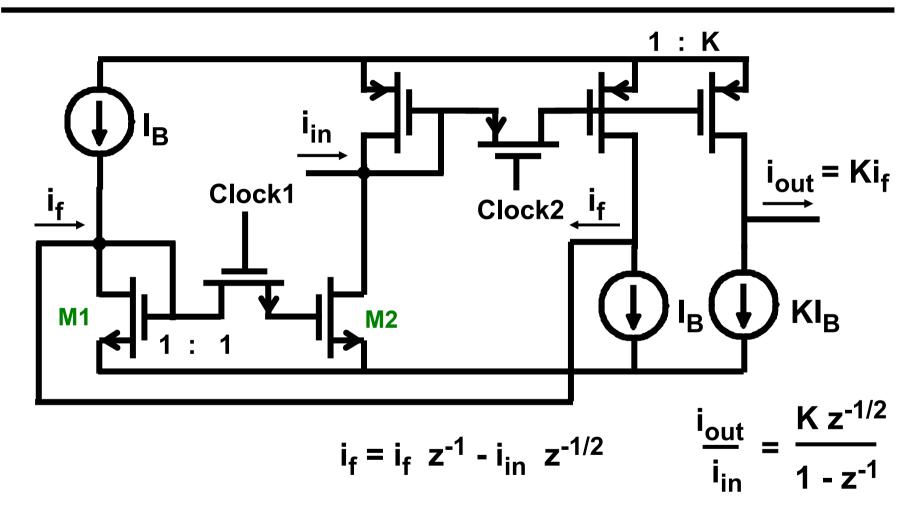


Switch closed : track V_{GS} $I_{out} = I_{in}$

Switch open : hold V_{GS} $I_{out} = I_{in} (\Delta T_c)$ $I_{out} = I_{in} z^{-1/2}$

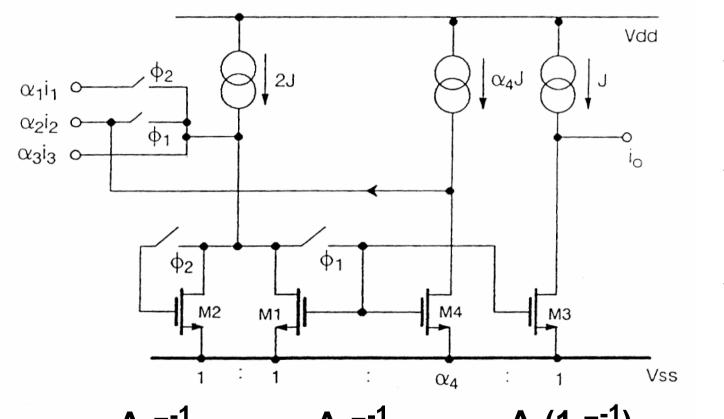
Ref. Zele JSSC Feb. 96, 157-168

Switched-current low-pass filter



Ref. Zele JSSC Feb. 96, 157-168

2nd-generation switched-current filter



$$A_1 = \frac{\alpha_1}{1 + \alpha_4}$$

$$A_2 = \frac{\alpha_2}{1 + \alpha_4}$$

$$A_3 = \frac{\alpha_3}{1 + \alpha_4}$$

$$B = \frac{1}{1 + \alpha_4}$$

$$i_o(z) = \frac{A_1 z^{-1}}{1 - B z^{-1}} i_1(z) - \frac{A_2 z^{-1}}{1 - B z^{-1}} i_2(z) - \frac{A_3 (1 - z^{-1})}{1 - B z^{-1}} i_3(z)$$

Comparison SC - SI

SC

SI

Signal: Voltage

Charge on linear C

Q = C V

Accuracy: Capacitor ratio

0.2 %

Amps: Opamps

S/N+D 70 dB

Current

Charge on MOST C_{GS}

Q = It

MOST area ratio

2 %

Current mirrors

50 dB

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